

Not Recommended for New Designs

This product was manufactured for Maxim by an outside wafer foundry using a process that is no longer available. It is not recommended for new designs. The data sheet remains available for existing users.

A Maxim replacement or an industry second-source may be available. Please see the QuickView data sheet for this part or contact technical support for assistance.

For further information, [contact Maxim's Applications Tech Support](#).

Features

- ✦ 15V/ μ s Min Slew Rate
- ✦ +3V Single-Supply Operation
- ✦ Guaranteed 10MHz Unity-Gain Bandwidth
- ✦ 2mA Supply Current per Amplifier
- ✦ Input Range Includes Negative Rail
- ✦ Outputs Short-Circuit Protected
- ✦ Rail-to-Rail Output Swing (to within $\pm 50\text{mV}$)
- ✦ μ MAX Package (the smallest 8-pin SO)

Ordering Information

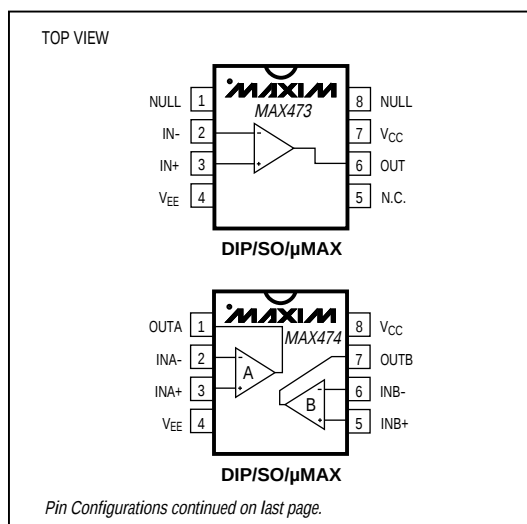
Ordering Information continued on last page.

* Dice are specified at $T_A = +25^\circ\text{C}$. DC parameters only.

Applications

- Portable Equipment
- Battery-Powered Instruments
- Signal Processing
- Discrete Filters
- Signal Conditioning
- Servo-Loops

Pin Configurations



Single/Dual/Quad, 10MHz Single-Supply Op Amps

ABSOLUTE MAXIMUM RATINGS

Supply Voltage ($V_{CC} - V_{EE}$) 7V
 Input Voltage ($IN+$, $IN-$, IN_+ , IN_-) ($V_{CC} + 0.3V$)
 to ($V_{EE} - 0.3V$)
 Output Short-Circuit Duration Continuous
 Continuous Power Dissipation ($T_A = +70^\circ C$)
 8-Pin Plastic DIP (derate 9.09mW/ $^\circ C$ above $+70^\circ C$) ... 727mW
 8-Pin SO (derate 5.88mW/ $^\circ C$ above $+70^\circ C$) 471mW
 8-Pin μ MAX (derate 4.1mW/ $^\circ C$ above $+70^\circ C$) 330mW
 8-Pin Cerdip (derate 8.00mW/ $^\circ C$ above $+70^\circ C$) 640mW
 14-Pin Plastic DIP (derate 10.00mW/ $^\circ C$ above $+70^\circ C$) ... 800mW

14-Pin SO (derate 8.33mW/ $^\circ C$ above $+70^\circ C$) 667mW
 14-Pin Cerdip (derate 9.09mW/ $^\circ C$ above $+70^\circ C$) 727mW
 Operating Temperature Ranges
 MAX47_C_ $0^\circ C$ to $+70^\circ C$
 MAX47_E_ $-40^\circ C$ to $+85^\circ C$
 MAX47_MJ $-55^\circ C$ to $+125^\circ C$
 Junction Temperatures
 MAX47_C_/E_ $+150^\circ C$
 MAX47_MJ $+175^\circ C$
 Storage Temperature Range $-65^\circ C$ to $+160^\circ C$
 Lead Temperature (soldering, 10sec) $+300^\circ C$

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

($+3V \leq V_{CC} \leq +5V$, $V_{EE} = 0V$, $V_{CM} = 0.5V$, $V_{OUT} = 0.5V$, $T_A = +25^\circ C$, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Input Offset Voltage	V_{OS}	MAX473		± 0.70	± 2.0	mV
		MAX474		± 0.70	± 2.0	
		MAX475		± 0.80	± 2.5	
Input Bias Current	I_B	Current flows out of terminals	0	80	150	nA
Input Offset Current	I_{OS}			± 10	± 30	nA
Common-Mode Voltage	V_{CM}	High	$V_{CC} - 1.9$	$V_{CC} - 1.7$		V
		Low		$V_{EE} - 0.1$	V_{EE}	
Common-Mode Rejection Ratio	CMRR	$V_{EE} \leq V_{CM} \leq (V_{CC} - 1.9V)$	80	90		dB
Power-Supply Rejection Ratio	PSRR	$V_{CC} = 2.7V$ to $6.0V$	80	90		dB
Input Noise-Voltage Density	e_n	$f = 10kHz$		40		nV/ $\sqrt{Hz}$
Large-Signal Gain (Note 1)	A_{VOL}	$0.3V \leq V_{OUT} \leq (V_{CC} - 0.5V)$	$R_L = \text{no load}$	110		dB
			$R_L = 10k\Omega$	94	105	
			$R_L = 600\Omega$	82	90	
		Sinking 5mA	$V_{CC} = 5V$	76		
			$V_{CC} = 3V$	100		
		Sourcing 5mA	$V_{CC} = 5V$	76		
			$V_{CC} = 3V$	90		
Output Voltage	V_{OH}	$V_{IN+} - V_{IN-} = +1V$, $R_L = \text{no load}$	$V_{CC} - 0.05$			V
	V_{OL}	$V_{IN+} - V_{IN-} = -1V$, $R_L = \text{no load}$		$V_{EE} + 0.05$		
Slew Rate	SR	$V_{CC} = 5V$, $R_L = 10k\Omega$, $C_L = 20pF$, $V_{IN+} - V_{IN-} = +1V$ step	15	17		V/ μs
Unity-Gain Bandwidth (Note 2)	GBW	$3V \leq V_{CC} \leq 5V$	10	12		MHz
		$V_{CC} = 2.7V$		10		

Single/Dual/Quad, 10MHz Single-Supply Op Amps

MAX473/MAX474/MAX475

ELECTRICAL CHARACTERISTICS (continued)

($+3V \leq V_{CC} \leq +5V$, $V_{EE} = 0V$, $V_{CM} = 0.5V$, $V_{OUT} = 0.5V$, $T_A = +25^\circ C$, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Settling Time	t_s	To 0.1%, $C_L = 20pF$		400		ns
Power-Up Time	t_{PU}	$A_V = +1$, $V_{IN} = 1/2 V_{CC}$ step, see <i>Typical Operating Characteristics</i>		700		ns
Overshoot		$C_L = 150pF$		10		%
		$C_L = 20pF$		5		
Phase Margin		$R_L = 10k\Omega$, $C_L = 20pF$	$V_{CC} = 5V$	63		degrees
			$V_{CC} = 3V$	58		
Gain Margin		$R_L = 10k\Omega$, $C_L = 20pF$	$V_{CC} = 5V$	10		dB
			$V_{CC} = 3V$	12		
Supply Current	I_S	Per amplifier		2.0	3.0	mA
Operating Supply-Voltage Range		Single supply	2.7		5.25	V
		Dual supplies	± 1.35		± 2.625	

ELECTRICAL CHARACTERISTICS

($+3V \leq V_{CC} \leq +5V$, $V_{EE} = 0V$, $V_{CM} = 0.5V$, $V_{OUT} = 0.5V$, $T_A = 0^\circ C$ to $+70^\circ C$, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Input Offset Voltage	V_{OS}	MAX473			± 2.0	mV
		MAX474			± 2.0	
		MAX475			± 3.0	
Input Bias Current	I_B	Current flows out of terminals	0		175	nA
Input Offset Current	I_{OS}				± 35	nA
Common-Mode Rejection Ratio	CMRR	$V_{EE} \leq V_{CM} \leq (V_{CC} - 1.9V)$	78			dB
Power-Supply Rejection Ratio	PSRR	$V_{CC} = 2.7V$ to $6.0V$	78			dB
Large-Signal Gain (Note 1)	A_{VOL}	$0.4V \leq V_{OUT} \leq (V_{CC} - 0.6V)$	$R_L = 10k\Omega$	94		dB
			$R_L = 600\Omega$	80		
Output Voltage	V_{OH}	$V_{IN+} - V_{IN-} = +1V$, $R_L =$ no load	$V_{CC} - 0.07$			V
	V_{OL}	$V_{IN+} - V_{IN-} = -1V$, $R_L =$ no load		$V_{EE} + 0.07$		
Slew Rate	SR	$V_{CC} = 5V$, $R_L = 10k\Omega$, $C_L = 20pF$, $V_{IN+} - V_{IN-} = +1V$ step	12			V/ μs
Supply Current	I_S	Per amplifier			3.3	mA
Operating Supply-Voltage Range		Single supply	2.7		5.25	V
		Dual supplies	± 1.35		± 2.625	

Single/Dual/Quad, 10MHz Single-Supply Op Amps

ELECTRICAL CHARACTERISTICS

(+3V ≤ V_{CC} ≤ +5V, V_{EE} = 0V, V_{CM} = 0.5V, V_{OUT} = 0.5V, T_A = -40°C to +85°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Input Offset Voltage	V _{OS}	MAX473			±2.3	mV
		MAX474			±2.3	
		MAX475			±3.3	
Input Bias Current	I _B	Current flows out of terminals	0		200	nA
Input Offset Current	I _{OS}				±50	nA
Common-Mode Rejection Ratio	CMRR	V _{EE} ≤ V _{CM} ≤ (V _{CC} - 2.0V)	72			dB
Power-Supply Rejection Ratio	PSRR	V _{CC} = 2.7V to 6.0V	72			dB
Large-Signal Gain (Note 1)	A _{VOL}	0.4V ≤ V _{OUT} ≤ (V _{CC} - 0.6V)				dB
		R _L = 10kΩ R _L = 600Ω	94 72			
Output Voltage	V _{OH}	V _{IN+} - V _{IN-} = +1V, R _L = no load	V _{CC} - 0.08			V
	V _{OL}	V _{IN+} - V _{IN-} = -1V, R _L = no load		V _{EE} + 0.08		
Slew Rate	SR	V _{CC} = 5V, R _L = 10kΩ, C _L = 20pF, V _{IN+} - V _{IN-} = +1V step	10			V/μs
Supply Current	I _S	Per amplifier			3.4	mA
Operating Supply-Voltage Range		Single supply	2.7		5.25	V
		Dual supplies	±1.35		±2.625	

ELECTRICAL CHARACTERISTICS

(+3V ≤ V_{CC} ≤ +5V, V_{EE} = 0V, V_{CM} = 0.5V, V_{OUT} = 0.5V, T_A = -55°C to +125°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Input Offset Voltage	V _{OS}	MAX473			±2.8	mV
		MAX474			±2.8	
		MAX475			±4.0	
Input Bias Current	I _B	Current flows out of terminals	0		225	nA
Input Offset Current	I _{OS}				±60	nA
Common-Mode Rejection Ratio	CMRR	V _{EE} ≤ V _{CM} ≤ (V _{CC} - 2.15V)	70			dB
Power-Supply Rejection Ratio	PSRR	V _{CC} = 2.7V to 6.0V	70			dB
Large-Signal Gain (Note 1)	A _{VOL}	0.5V ≤ V _{OUT} ≤ (V _{CC} - 0.6V)				dB
		R _L = 10kΩ R _L = 600Ω	90 70			
Output Voltage	V _{OH}	V _{IN+} - V _{IN-} = +1V, R _L = no load	V _{CC} - 0.1			V
	V _{OL}	V _{IN+} - V _{IN-} = -1V, R _L = no load		V _{EE} + 0.1		
Slew Rate	SR	V _{CC} = 5V, R _L = 10kΩ, C _L = 20pF, V _{IN+} - V _{IN-} = +1V step	9			V/μs
Supply Current	I _S	Per amplifier			3.6	mA
Operating Supply-Voltage Range		Single supply	2.7		5.25	V
		Dual supplies	±1.35		±2.625	

Note 1: Gain decreases to zero as the output swings beyond the specified limits.

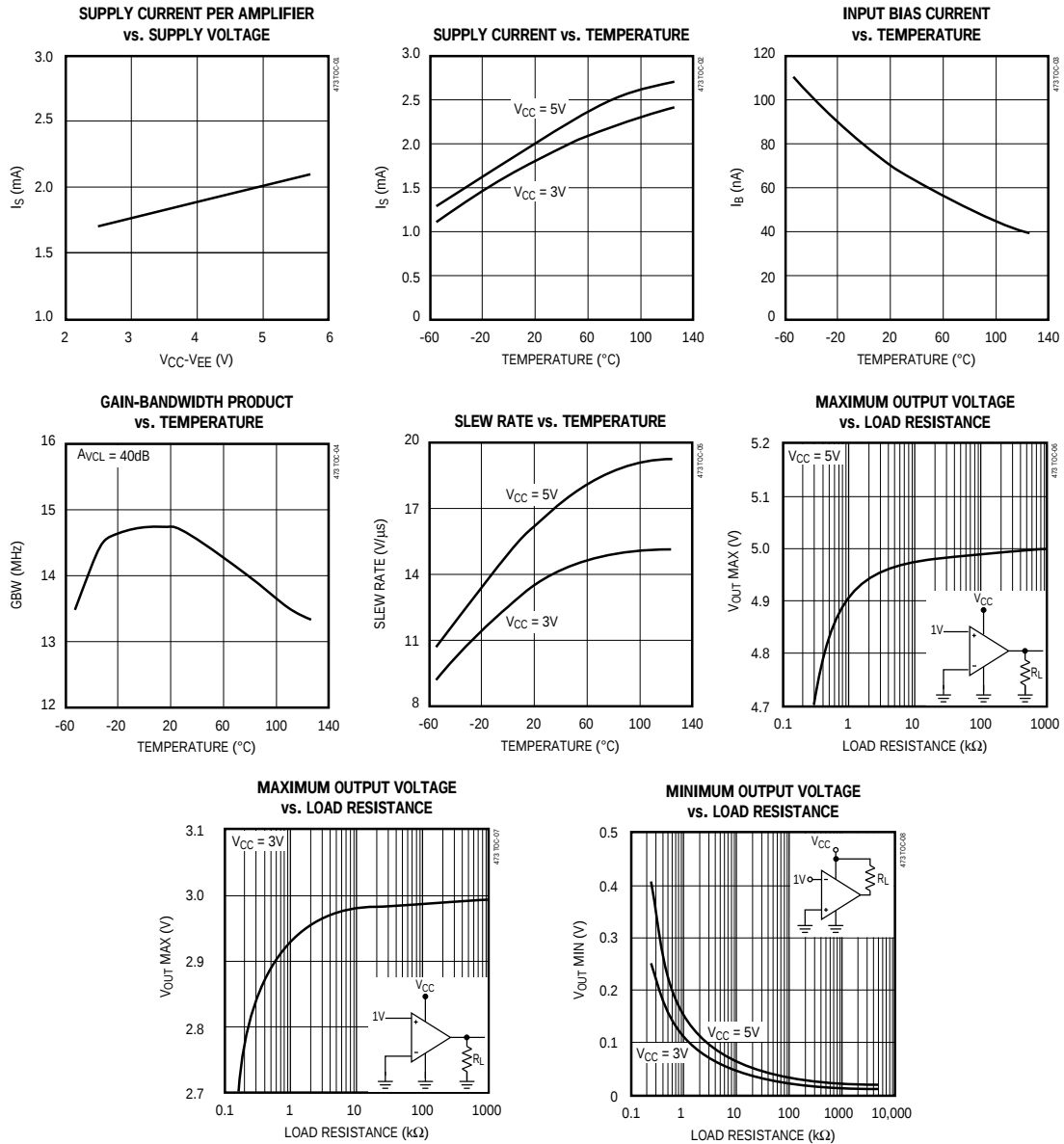
Note 2: Guaranteed by correlation to slew rate.

Single/Dual/Quad, 10MHz Single-Supply Op Amps

Typical Operating Characteristics

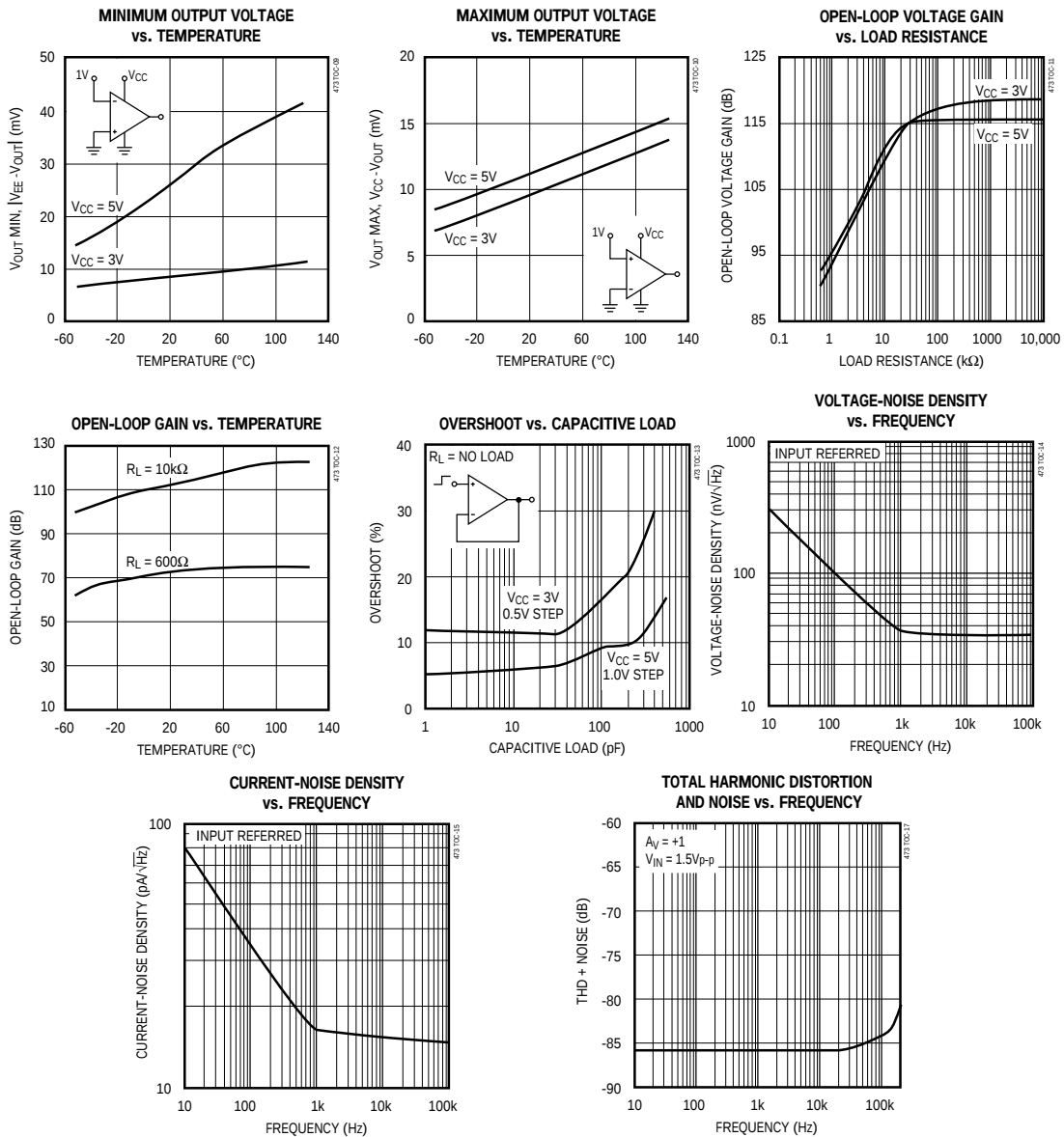
($V_{CC} = 5V$, $V_{EE} = 0V$, $T_A = +25^\circ C$, unless otherwise noted.)

MAX473/MAX474/MAX475



Single/Dual/Quad, 10MHz Single-Supply Op Amps

Typical Operating Characteristics (continued)
($V_{CC} = 5V$, $V_{EE} = 0V$, $T_A = +25^\circ C$, unless otherwise noted.)

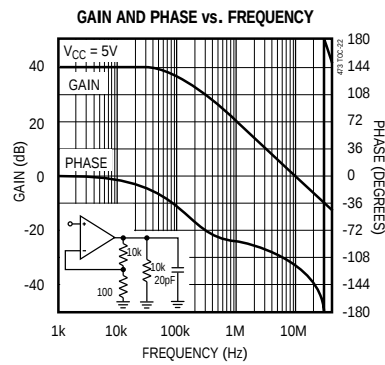
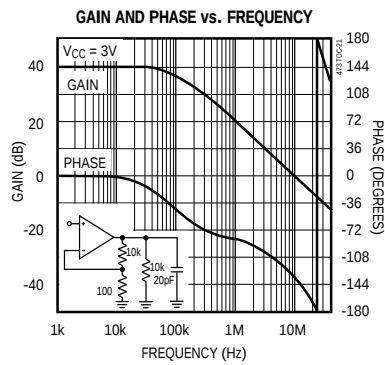
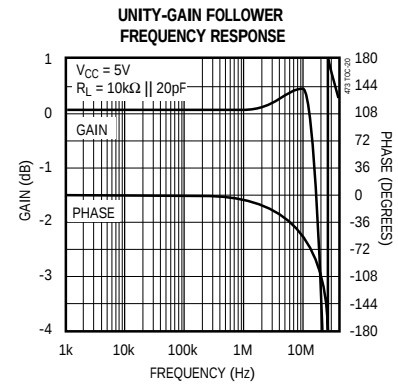
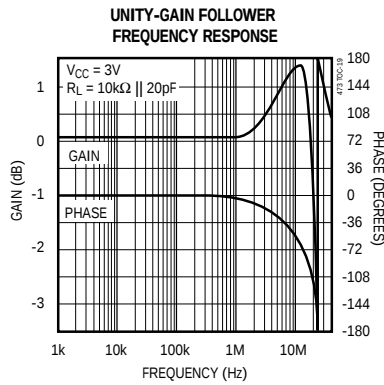
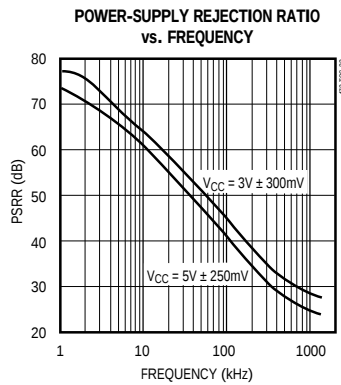


Single/Dual/Quad, 10MHz Single-Supply Op Amps

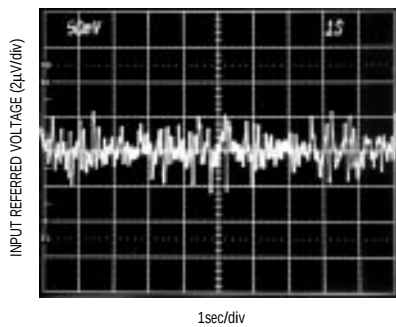
Typical Operating Characteristics (continued)

($V_{CC} = 5V$, $V_{EE} = 0V$, $T_A = +25^\circ C$, unless otherwise noted.)

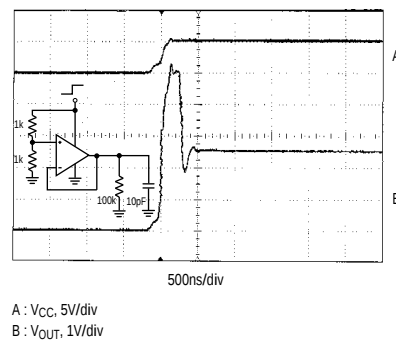
MAX473/MAX474/MAX475



0.1Hz to 10Hz VOLTAGE NOISE



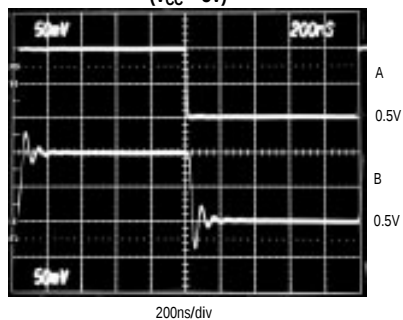
POWER-UP TIME



Single/Dual/Quad, 10MHz Single-Supply Op Amps

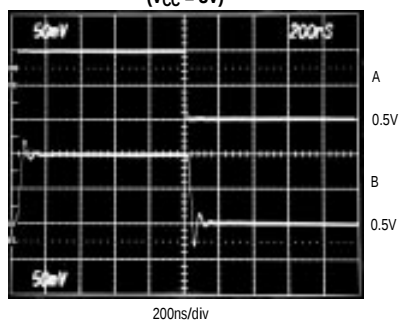
Typical Operating Characteristics (continued)
($V_{CC} = 5V$, $V_{EE} = 0V$, $T_A = +25^\circ C$, unless otherwise noted.)

SMALL-SIGNAL TRANSIENT RESPONSE
($V_{CC} = 5V$)



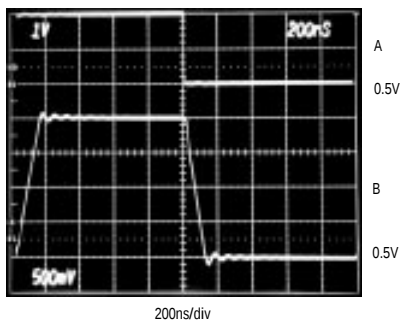
$V_{CC} = 5V$, $A_V = +1$, $R_L = 10k\Omega$, $C_L = 220pF$
A : V_{IN} , 50mV/div
B : V_{OUT} , 50mV/div

SMALL-SIGNAL TRANSIENT RESPONSE
($V_{CC} = 3V$)



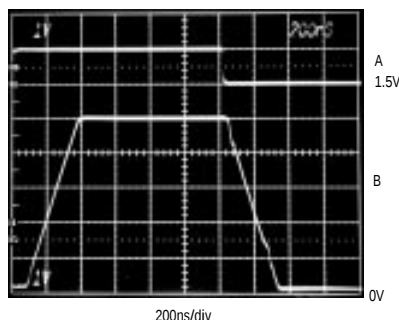
$V_{CC} = 3V$, $A_V = +1$, $R_L = 10k\Omega$, $C_L = 100pF$
A : V_{IN} , 50mV/div
B : V_{OUT} , 50mV/div

LARGE-SIGNAL TRANSIENT RESPONSE



$V_{CC} = 5V$, $A_V = +1$, $R_L = 10k\Omega$, $C_L = 220pF$
A : V_{IN} , 1V/div
B : V_{OUT} , 500mV/div

OVERDRIVING THE OUTPUT



$V_{CC} = 5V$, $V_{IN-} = 2.0V$, $R_L = 10k\Omega$, $C_L = 33pF$
A : V_{IN+} , 1V/div
B : V_{OUT} , 1V/div

Single/Dual/Quad, 10MHz Single-Supply Op Amps

Pin Description

MAX473/MAX474/MAX475

PIN			NAME	FUNCTION
MAX473	MAX474	MAX475		
1, 8	—	—	NULL	Offset Null Input. Connect to one end of 2k Ω potentiometer for offset voltage trimming. Connect wiper to V _{EE} . See Figure 1.
—	1	1	OUTA	Amplifier A Output
2	—	—	IN-	Inverting Input
—	2	2	INA-	Amplifier A Inverting Input
3	—	—	IN+	Noninverting Input
—	3	3	INA+	Amplifier A Noninverting Input
4	4	11	V _{EE}	Negative Power-Supply Pin. Connect to ground or a negative voltage.
5	—	—	N.C.	No Connect—not internally connected
—	5	5	INB+	Amplifier B Noninverting Input
6	—	—	OUT	Amplifier Output
—	6	6	INB-	Amplifier B Inverting Input
—	7	7	OUTB	Amplifier B Output
7	8	4	V _{CC}	Positive Power-Supply Pin. Connect to (+) terminal of power supply.
—	—	8	OUTC	Amplifier C Output
—	—	9	INC-	Amplifier C Inverting Input
—	—	10	INC+	Amplifier C Noninverting Input
—	—	12	IND+	Amplifier D Noninverting Input
—	—	13	IND-	Amplifier D Inverting Input
—	—	14	OUTD	Amplifier D Output

Applications Information

Power Supplies

The MAX473/MAX474/MAX475 operate from a single 2.7V to 5.25V power supply, or from dual supplies of $\pm 1.35V$ to $\pm 2.625V$. For single-supply operation, bypass the power supply with 0.1 μF . If operating from dual supplies, bypass each supply to ground. With 0.1 μF bypass capacitance, channel separation (MAX474/MAX475) is typically better than 120dB with signal frequencies up to 300kHz. Increasing the bypass capacitance (e.g. 10 μF || 0.1 μF) maintains channel separation at higher frequencies.

Minimizing Offsets

The MAX473's maximum offset voltage is $\pm 2mV$ ($T_A = +25^\circ C$). If additional offset adjustment is required, connect a 2k Ω trim potentiometer between pins 1, 8, and 4 (Figure 1). Input offset voltage for the dual MAX474 and quad MAX475 cannot be externally trimmed.

The MAX473/MAX474/MAX475 are bipolar op amps with low input bias currents. The bias currents at both inputs flow out of the device. Matching the resistance at the op amp's inputs significantly reduces the offset error caused by the bias currents. Place a resistor (R3) from the noninverting input to ground when using the inverting configuration (Figure 2a); place R3 in series with the noninverting input when using the noninverting configuration (Figure 2b). Select R3 such that the parallel combination of R2 and R1 equals R3. Adding R3 will slightly increase the op amp's voltage noise.

Output Loading and Stability

The MAX473/MAX474/MAX475 op amps are unity-gain stable. Any op amp's stability depends on the configuration, closed-loop gain, and load capacitance. The unity-gain, noninverting buffer is the most sensitive gain configuration, and driving capacitive loads decreases stability.

Single/Dual/Quad, 10MHz Single-Supply Op Amps

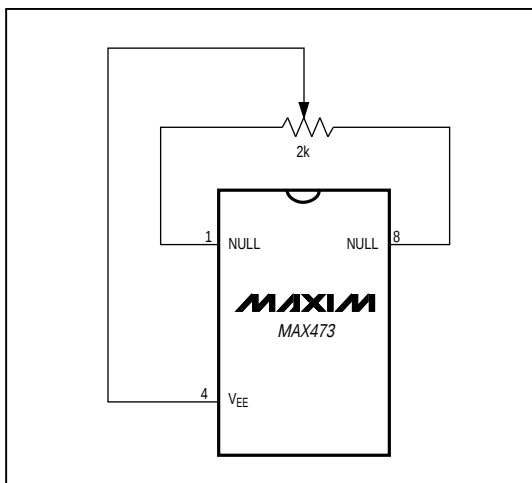


Figure 1. Offset Null Circuit

The MAX473/MAX474/MAX475 have excellent phase margin (the difference between 180° and the unity-gain phase angle). It is typically 63° with a load of 10kΩ in parallel with 20pF. Generally, higher phase margins indicate greater stability.

Capacitive loads form an RC network with the op amp's output resistance, causing additional phase shift that reduces the phase margin. Figure 3 shows the MAX473/MAX474/MAX475 output response when driving a 390pF load in parallel with 10kΩ.

When driving large capacitive loads, add an output isolation resistor, as shown in Figure 4. This resistor improves the phase margin by isolating the load capacitance from the amplifier output. Figure 5 shows the MAX473/MAX474/MAX475 driving a capacitive load of 1000pF using the circuit of Figure 4.

Feedback Resistors

The feedback resistors appear as a resistance network to the op amp's feedback input (Figure 2). This resistance, combined with the op amp's input and stray capacitance (total input capacitance), forms a pole that adds unwanted phase shift when either the total input capacitance or feedback resistance is too large. For example, using the noninverting configuration with a gain of 10, if the total capacitance at the negative input is 10pF and the effective resistance ($R1 \parallel R2$) is 9kΩ, this RC network introduces a pole at $f_0 = 1.8\text{MHz}$. At

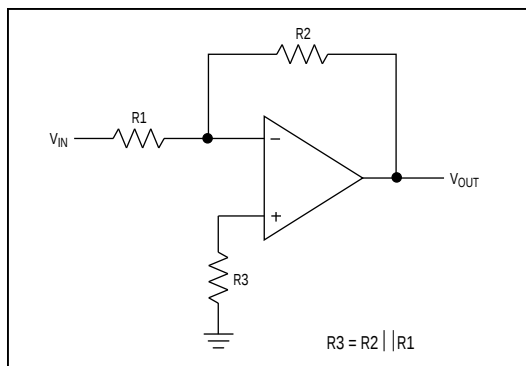


Figure 2a. Reducing Offset Error Due to Bias Current: Inverting Configuration

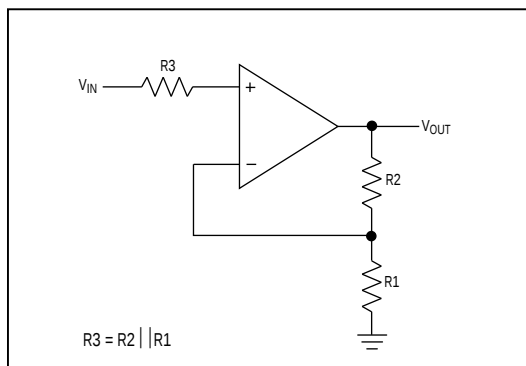


Figure 2b. Reducing Offset Error Due to Bias Current: Noninverting Configuration

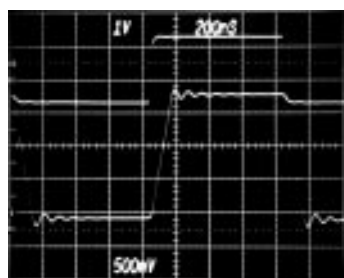
input frequencies above f_0 , the pole introduces additional phase shift, which reduces the overall bandwidth and adversely affects stability. Choose feedback resistors small enough so they do not adversely affect the op amp's operation at the frequencies of interest.

Overdriving the Outputs

The output voltage swing for specified operation is from ($V_{EE} + 0.3\text{V}$) to ($V_{CC} - 0.5\text{V}$) (see *Electrical Characteristics*). Exercising the outputs beyond these limits drives the output transistors toward saturation, resulting in bandwidth degradation, response-time increase, and gain decrease (which affects linearity). Operation in this region causes a slight distortion in the output waveform, but does not adversely affect the op amp.

Single/Dual/Quad, 10MHz Single-Supply Op Amps

MAX473/MAX474/MAX475



Driving 390pF in parallel with 10kΩ,
V_{CC} = 5V, buffer configuration

Figure 3. MAX474 Driving 390pF

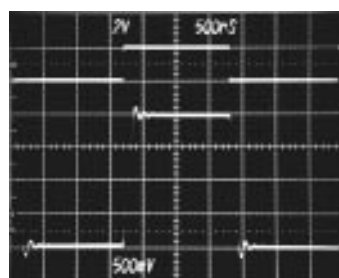


Figure 5. The MAX473 easily drives 1000pF using the
Capacitive-Load Driving Circuit (Figure 4).

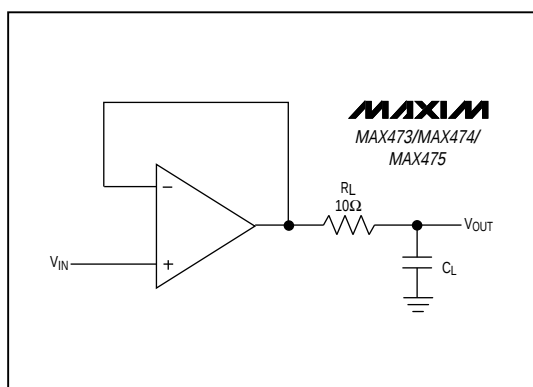


Figure 4. Capacitive-Load Driving Circuit

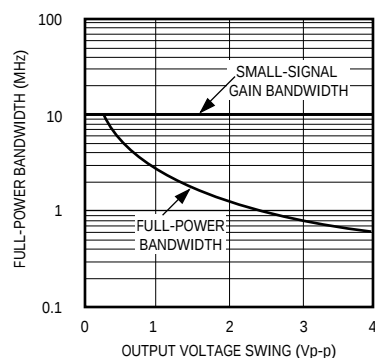


Figure 6. Full-Power Bandwidth vs. Peak-to-Peak AC Voltage

Full-Power Bandwidth

The MAX473/MAX474/MAX475's fast 15V/μs slew rate maximizes full-power bandwidth (FPBW). The FPBW is given by:

$$\text{FPBW (Hz)} = \frac{\text{SR}}{\pi [\text{V}_{\text{OUT peak-to-peak(max)}}]}$$

where the slew rate (SR) is 15V/μs min. Figure 6 shows the full-power bandwidth as a function of the peak-to-peak AC output voltage.

Layout

A good layout improves performance by decreasing the amount of stray capacitance at the amplifier's inputs and output. Since stray capacitance might be unavoidable, minimize trace lengths and resistor leads, and place external components as close to the pins as possible.

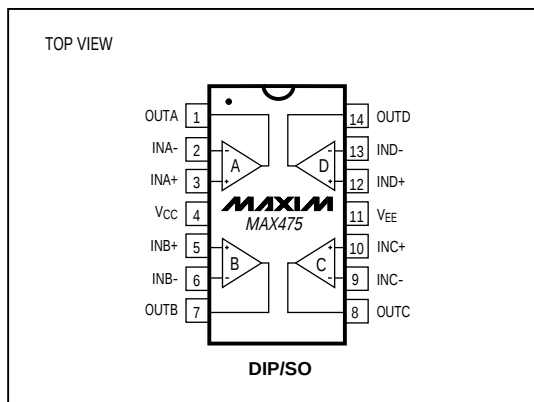
Single/Dual/Quad, 10MHz Single-Supply Op Amps

Ordering Information (continued)

PART	TEMP. RANGE	PIN-PACKAGE
MAX474CPA	0°C to +70°C	8 Plastic DIP
MAX474CSA	0°C to +70°C	8 SO
MAX474CUA	0°C to +70°C	8 μ MAX
MAX474C/D	0°C to +70°C	Dice*
MAX474EPA	-40°C to +85°C	8 Plastic DIP
MAX474ESA	-40°C to +85°C	8 SO
MAX474MJA	-55°C to +125°C	8 CERDIP
MAX475CPD	0°C to +70°C	14 Plastic DIP
MAX475CSD	0°C to +70°C	14 SO
MAX475EPD	-40°C to +85°C	14 Plastic DIP
MAX475ESD	-40°C to +85°C	14 SO
MAX475MJD	-55°C to +125°C	14 CERDIP

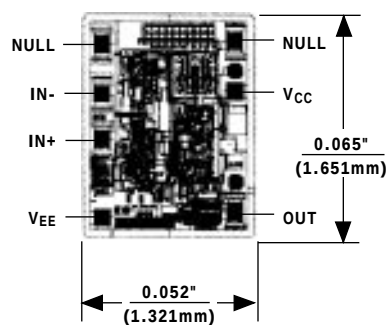
* Dice are specified at $T_A = +25^\circ\text{C}$, DC parameters only.

Pin Configurations (continued)



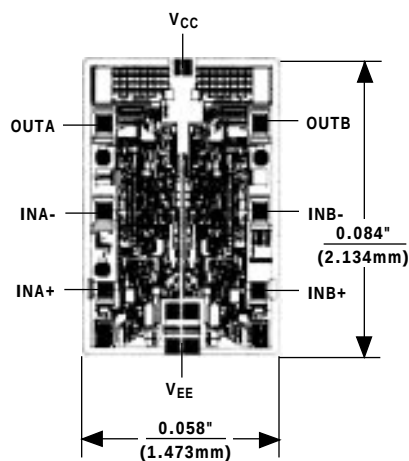
Chip Topographies

MAX473



TRANSISTOR COUNT: 185
SUBSTRATE CONNECTED TO VEE

MAX474



TRANSISTOR COUNT: 355
SUBSTRATE CONNECTED TO VEE

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[MAX473EPA+](#) [MAX473ESA](#) [MAX473ESA+](#) [MAX473ESA+T](#) [MAX473ESA-T](#) [MAX473MJA](#) [MAX474CPA](#)
[MAX474CPA+](#) [MAX474CSA](#) [MAX474CSA+](#) [MAX474CSA+T](#) [MAX474CSA-T](#) [MAX474CUA](#) [MAX474CUA+](#)
[MAX474EPA](#) [MAX474EPA+](#) [MAX474ESA](#) [MAX474ESA+](#) [MAX474ESA+T](#) [MAX474ESA-T](#) [MAX474MJA](#)
[MAX473C/D](#) [MAX473CUA-T](#) [MAX474C/D](#) [MAX474CUA+T](#) [MAX474CUA-T](#) [MAX475CSD](#) [MAX475CSD-T](#)
[MAX475ESD](#)